# PBSS5240T-Q

## 40 V, 2 A PNP low VCEsat transistor

3 January 2022

**Product data sheet** 

## 1. General description

PNP low  $V_{CEsat}$  transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4240T-Q

### 2. Features and benefits

- · Low collector-emitter saturation voltage
- High current capability
- Improved device reliability due to reduced heat generation
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

### 3. Applications

- Supply line switching circuits
- · Battery management applications
- DC/DC converter applications
- · Strobe flash units
- Heavy duty battery powered equipment (motor and lamp drivers).

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-40	V
I <sub>C</sub>	collector current			-	-	-2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	-3	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = -500 mA; $I_B$ = -50 mA; $T_{amb}$ = 25 °C	[1]	-	140	220	mΩ

[1] Device mounted on a printed-circuit board, single sided copper, tin plated, standard footprint.



## 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	]3	
2	Е	emitter		C
3	С	collector		В
			SOT23	   E   sym132

## 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
PBSS5240T-Q		plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5240T-Q	ZF%

[1] % = placeholder for manufacturing site code

## 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-40	V
$V_{CEO}$	collector-emitter voltage	open base		-	-40	V
$V_{EBO}$	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-3	А
I <sub>BM</sub>	peak base current			-	-300	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
			[2]	-	480	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

### 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uig-a)	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W
			[2]	-	-	260	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = -100 μA; I <sub>E</sub> = 0 A		-40	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = -10 mA; I <sub>B</sub> = 0 A		-40	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage (collector open)	I <sub>E</sub> = -100 μA; I <sub>C</sub> = 0 A		-5	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 \text{ °C}$		-	-	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -4 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -2 V; $I_{C}$ = -100 mA; $T_{amb}$ = 25 °C		300	450	-	
		$V_{CE}$ = -2 V; $I_{C}$ = -500 mA; $T_{amb}$ = 25 °C		260	350	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -1 A; T <sub>amb</sub> = 25 °C		210	290	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -2 A; T <sub>amb</sub> = 25 °C		100	180	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -100 mA; $I_B$ = -1 mA; $T_{amb}$ = 25 °C		-	-55	-100	mV
		$I_C$ = -500 mA; $I_B$ = -50 mA; $T_{amb}$ = 25 °C		-	-70	-110	mV
		$I_C$ = -750 mA; $I_B$ = -15 mA; $T_{amb}$ = 25 °C		-	-140	-225	mV
		I <sub>C</sub> = -1 A; I <sub>B</sub> = -50 mA; T <sub>amb</sub> = 25 °C		-	-140	-225	mV
		I <sub>C</sub> = -2 A; I <sub>B</sub> = -200 mA; T <sub>amb</sub> = 25 °C		-	-240	-350	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C = -500 \text{ mA}$ ; $I_B = -50 \text{ mA}$ ; $T_{amb} = 25 \text{ °C}$	[1]	-	140	220	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C = -2 \text{ A}; I_B = -200 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	-1.1	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; I_{C} = -100 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	-0.75	V
f⊤	transition frequency	$V_{CE}$ = -10 V; $I_{C}$ = -100 mA; f = 100 MHz; $T_{amb}$ = 25 °C		100	200	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	23	28	pF

<sup>[1]</sup> Device mounted on a printed-circuit board, single sided copper, tin plated, standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

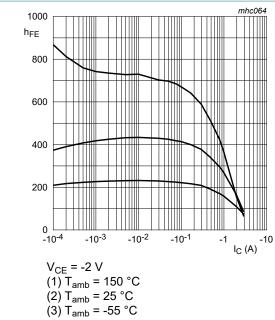
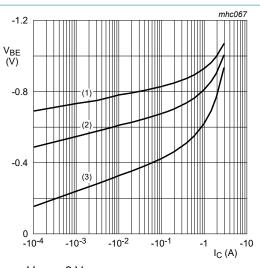
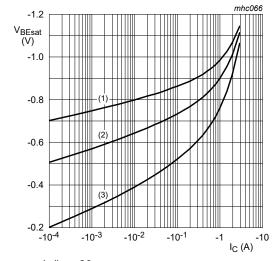


Fig. 1. DC current gain as a function of collector current; typical values



V<sub>CE</sub> = -2 V (1) T<sub>amb</sub> = -55 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 150 °C

Fig. 2. Base-emitter voltage as a function of collector current; typical values



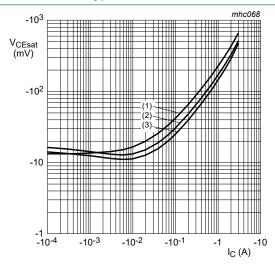
 $I_{\rm C}/I_{\rm B}=20$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 150 \, ^{\circ}C$ 

Fig. 3. Base-emitter saturation voltage as a function of | Fig. 4. collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ 

(1)  $T_{amb} = 150 \, ^{\circ}C$ 

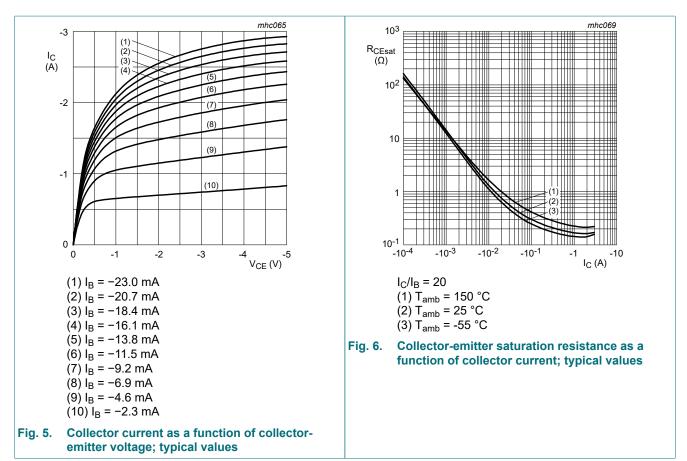
(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Collector-emitter saturation voltage as a function of collector current; typical values

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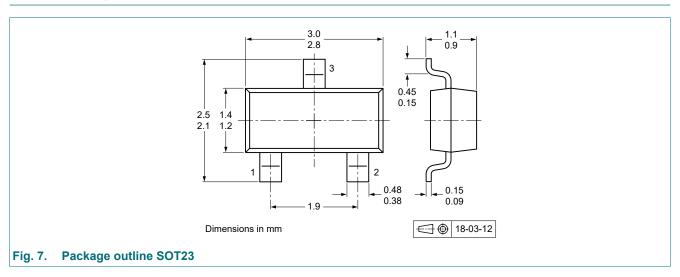


### 11. Test information

### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline

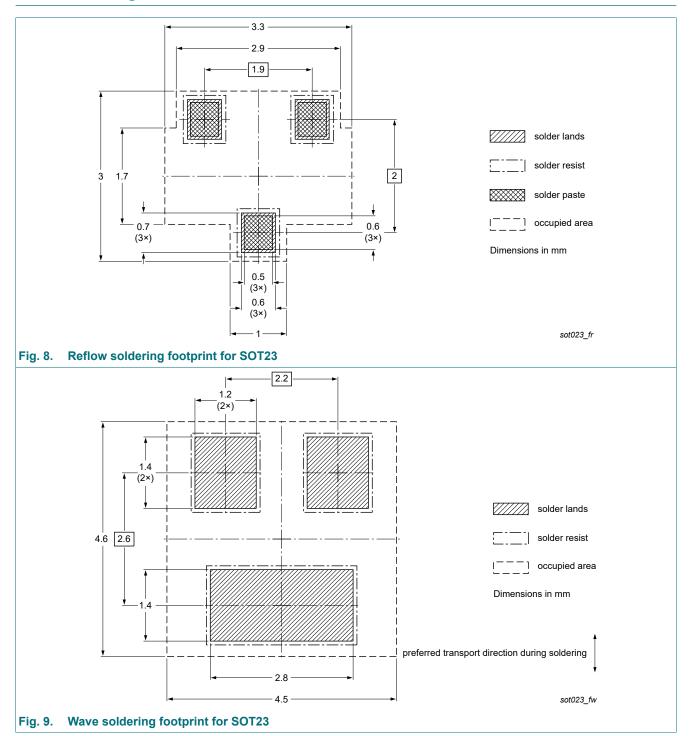


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## 13. Soldering



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## 14. Revision history

### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5240T-Q v.1	20220103	Product data sheet	-	-

### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## PBSS5240T-Q

### 40 V, 2 A PNP low VCEsat transistor

### **Contents**

1.	General description	. 1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	. 1
5.	Pinning information	. 2
6.	Ordering information	. 2
7.	Marking	. 2
8.	Limiting values	. 2
9.	Thermal characteristics	. 3
10.	Characteristics	. 3
11.	Test information	. 5
12.	Package outline	. 5
13.	Soldering	. 6
14.	Revision history	.7
	Legal information	

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